

## Spread Spectrum Clock Generator

## **Description**

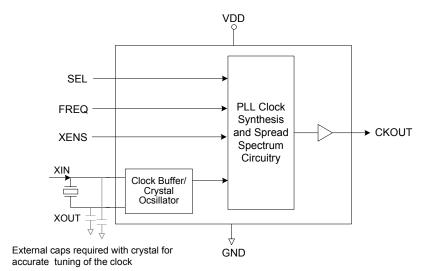
The ICS7152-01, -02, -11, and -12 are clock generators for EMI (Electro Magnetic Interference) reduction (see below for frequency ranges and multiplier ratios). Spectral peaks can be attenuated by making the oscillation frequency modulate slightly. Both down and center spread profiles are selectable. Down spread maintains an average frequency equal to an unspread clock, and down spread meets maximum frequency specs over the entire modualtion cycle.

ICS offers many other clocks for computers and computer peripherals. Consult ICS when you need to remove crystals and oscillators from your board.

#### **Features**

- Operating voltage of 3.3 V ±0.3 V
- Packaged in 8-pin SOIC
- Input frequency range of 16.6 to 134.0 MHz
- Output frequency range of 16.6 to 134.0 MHz
- Provides a spread spectrum clock output (±0.5%, ±1.5% center spread; -1.0%, -3.0% down spread)
- Input oscillation circuit: range of 16.6 to 48.0 MHz
- Low cycle-to-cycle jitter less than 100 ps
- Advanced, low-power CMOS process
- Industrial temperature range
- · Available in Pb (lead) free package

### **Block Diagram**

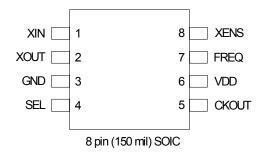


## **Product Lineup**

Product	Input Frequency Range	Modulation Type	Modulation Enable Pin
ICS7152M-01, ICS7152MI-01	16.6 MHz to 67 MHz	Down oproad	
ICS7152M-02, ICS7152MI-02	40.0 MHz to 134.0 MHz	Down spread	Yes
ICS7152M-11, ICS7152MI-11	16.6 MHz to 67.0 MHz	Contar aproad	res
ICS7152M-12, ICS7152MI-12	40.0 MHz to 134.0 MHz	Center spread	



## **Pin Assignment**



## **Modulation Enable Setting Table**

XENS Pin 8	Modulation
0	Modulation
1	No modulation

# **SEL Modulation Rate Setting Table**

SEL Pin 4 (note1)	Spread Direction	Spread Percentage (%)	Part Number
0	Center	±0.5	ICS7152M-11, ICS7152M-12
	Down	-1.0	ICS7152M-01, ICS7152M-02
1	Center	±1.5	ICS7152M-11, ICS7152M-12
	Down	-3.0	ICS7152M-01, ICS7152M-02

#### Notes:

1. The modulation rate can be changed at the level of the terminal.

## **Frequency Setting Table**

FREQ Pin 7	Freq	Frequency				
0	16.6 to 40 MHz	ICS7152M-01, ICS7152M-11				
	40 to 80 MHz	ICS7152M-02, ICS7152M-12				
1	33 to 67 MHz	ICS7152M-01, ICS7152M-11				
	66 to 134 MHz	ICS7152M-02, ICS7152M-12				

## **Pin Descriptions**

Pin Number	Pin Name	Pin Type	Pin Description
1	XIN	Input	Crystal resonator connection pin/clock input pin.
2	XOUT	Output	Crystal resonator connection pin.
3	GND	Power	Connect to ground.
4	SEL	Input	Modulation rate setting pin.
5	CKOUT	Output	Modulated clock output pin.
6	VDD	Power	Connect to +3.3 V.
7	FREQ	Input	Frequency setting pin.
8	XENS	Output	Modulation enable setting pin.



## **External Components**

The ICS7152 requires a minimum number of external components for proper operation.

#### **Decoupling Capacitor**

A decoupling capacitor of 0.01µF must be connected between GND and VDD on pins 3 and 6, as close to these pins as possible. For optimum device performance, the decoupling capacitor should be mounted on the component side of the PCB. Avoid the use of vias in the decoupling circuit.

#### **Series Termination Resistor**

Series termination should be used on the clock output. To series terminate a  $50\Omega$  trace (a commonly used trace impedance) place a  $5\Omega$  resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is  $45\Omega$ .

#### **PCB Layout Recommendations**

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

- 1) The  $0.01\mu F$  decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via.
- 2) To minimize EMI, the  $5\Omega$  series termination resistor (if needed) should be placed close to the clock output.
- 3) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers. Other signal traces should be routed away from the ICS7152. This includes signal traces just

underneath the device, or on layers adjacent to the ground plane layer used by the device.

#### **Crystal Information**

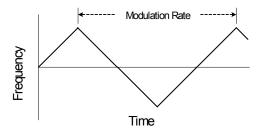
The crystal used should be a fundamental mode, parallel resonant. Crystal capacitors should be connected from pins X1 to ground and X2 to ground to optimize the initial accuracy. The value of these capacitors is given by the following equation:

Crystal caps (pF) = 
$$(C_L - 6) \times 2$$

In the equation,  $C_L$  is the crystal load capacitance. So, for a crystal with a 16 pF load capacitance, two 20 pF [(16-6) x 2] capacitors should be used.

#### **Spread Spectrum Profile**

The ICS7152 low EMI clock generator uses a triangular frequency modulation profile for optimal down stream tracking of zero delay buffers and other PLL devices. The frequency modulation amplitude is constant with variations of the input frequency.



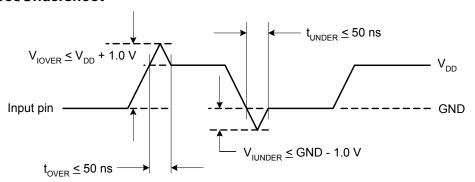


## **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the ICS7152. These ratings, which are standard values for ICS commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	-0.5 to 4.0 V
All Inputs and Outputs (referenced to GND)	-0.5 V to VDD+0.5 V
Ambient Operating Temperature	-40 to +85°C
Storage Temperature	-55 to +125°C
Junction Temperature	-40 to +125°C
Soldering Temperature	260°C
Overshoot (V <sub>IOVER</sub> )	VDD + 1.0 V (t <sub>OVER</sub> ≤ 50 ns) max
Undershoot (V <sub>IUNDER</sub> )	GND - 1.0 V (t <sub>UNDER</sub> ≤ 50 ns) min

#### Overshoot/Undershoot



# **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature	-40		+85	°C
Power Supply Voltage (measured in respect to GND)	+3.0	3.3	3.6	V



## **DC Electrical Characteristics**

Unless stated otherwise, **VDD = 3.3 V \pm 0.3 V**, Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		3.0	3.3	3.6	V
Supply Current	IDD	No load, at 3.3 V, output = 24 MHz		10	14	mA
Input High Voltage	V <sub>IH</sub>	SEL, FREQ, XENS	VDD x 0.8		VDD + 0.3	V
		XIN, Input slew rate 3 V/ns, 16.6 to 100 MHz	VDD x 0.8		VDD + 0.3	V
		XIN, Input slew rate 3 V/ns, 100 to 134 MHz	VDD x 0.9		VDD + 0.3	V
Input Low Voltage	$V_{IL}$	SEL, FREQ, XENS	GND		VDD x 0.20	V
		XIN, Input slew rate 3 V/ns, 16.6 to 100 MHz	GND		VDD x 0.20	V
		XIN, Input slew rate 3 V/ns, 100 to 134 MHz	GND		VDD x 0.10	V
Output High Voltage	V <sub>OH</sub>	CKOUT, I <sub>OH</sub> = -4 mA	VDD - 0.5		VDD	V
Output Low Voltage	V <sub>OL</sub>	CKOUT, I <sub>OL</sub> = 4 mA	GND		0.4	V
Input Capacitance	C <sub>IN</sub>	XIN, SEL, XENS			16	pF
		CKOUT, 16.6 to 67 MHz			15	pF
Load Capacitance	C <sub>L</sub>	CKOUT, 67 to 100 MHz			10	pF
		CKOUT, 100 to 134 MHz			7	pF
Output Impedance	Z <sub>O</sub>	CKOUT, 16.6 to 134 MHz		45		Ω



### **AC Electrical Characteristics**

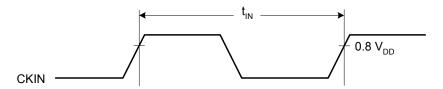
Unless stated otherwise, VDD = 3.3 V ±0.3 V, Ambient Temperature -40 to +85° C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Oscillation Frequency	f <sub>X</sub>	XIN, XOUT, Fundamental oscillation	16.6		40	MHz
		XIN, XOUT, 3rd over tone, note 1	40		48	MHz
Input Frequency	f <sub>IN</sub>	XIN, ICS7152-01, -11	16.6		67	MHz
		XIN, ICS7152-02, -12	40		134	MHz
Output Frequency	f <sub>OUT</sub>	CKOUT, ICS7152-01, -11	16.6		67	MHz
		CKOUT, ICS7152-02, -12	40		134	MHz
Input Clock Duty Cycle	t <sub>DCI</sub>	XIN, 16.6 to 100 MHz	40	50	60	%
		XIN, 100 to 134 MHz	45	50	55	%
Output Clock Duty Cycle	t <sub>DCC</sub>	CKOUT, 1.5 V	40		60	%
Output Slew Rate		CKOUT, 0.4 to 2.4 V, load capacitance 15 pF	0.5		3.0	V/ns
Cycle to Cycle Jitter	t <sub>JC</sub>	No load, standard deviation			100	ps
Lock-up Time	t <sub>LK</sub>	CKOUT		2	5	ms
Modulation Frequency	f <sub>MOD</sub>	CKOUT		33		kHz

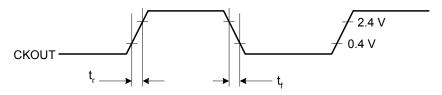
Note 1: Contact ICS Applications for more information.



## Input Frequency ( $f_{IN} = 1/t_{IN}$ )



### **Output Slew Rate**



 $SR = (2.4 - 0.4) / t_r$ ,  $SR = (2.4 - 0.4) / t_f$ 

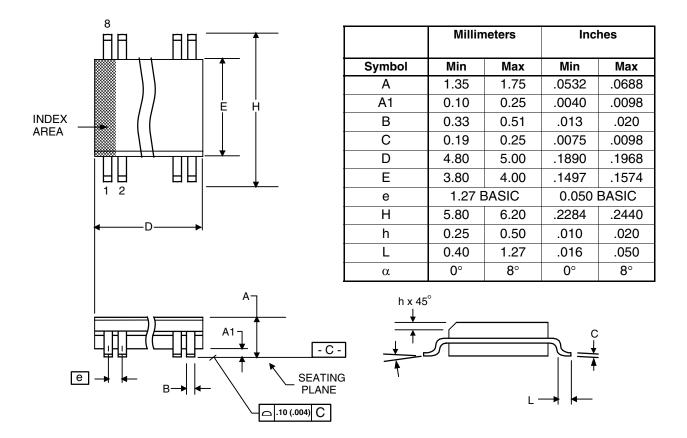
### **Thermal Characteristics 8 SOIC**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{\sf JA}$	Still air		150		°C/W
Ambient	$\theta_{\sf JA}$	1 m/s air flow		140		°C/W
	$\theta_{\sf JA}$	3 m/s air flow		120		°C/W
Thermal Resistance Junction to Case	$\theta_{\sf JC}$			40		°C/W



# Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Body)

Package dimensions are kept current with JEDEC Publication No. 95





### **Ordering Information**

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
ICS7152M-01	7152M-01	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-01T	7152M-01	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152M-01LF	7152M01L	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-01LFT	7152M01L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152MI-01	7152MI01	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-01T	7152MI01	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7152MI-01LF	7152I01L	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-01LFT	7152I01L	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7152M-02	7152M-02	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-02T	7152M-02	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152M-02LF	7152M02L	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-02LFT	7152M02L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152MI-02	7152MI02	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-02T	7152MI02	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7152MI-02LF	7152I02L	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-02LFT	7152I02L	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7152M-11	7152M-11	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-11T	7152M-11	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152M-11LF	7152M11L	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-11LFT	7152M11L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152MI-11	7152MI11	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-11T	7152MI11	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7152MI-11LF	7152l11L	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-11LFT	7152l11L	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7152M-12	7152M-12	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-12T	7152M-12	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152M-12LF	7152M12L	Tubes	8-pin SOIC	0 to +70° C
ICS7152M-12LFT	7152M12L	Tape and Reel	8-pin SOIC	0 to +70° C
ICS7152MI-12	7152MI12	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-12T	7152MI12	Tape and Reel	8-pin SOIC	-40 to +85° C
ICS7152MI-12LF	7152l12L	Tubes	8-pin SOIC	-40 to +85° C
ICS7152MI-12LFT	7152l12L	Tape and Reel	8-pin SOIC	-40 to +85° C

#### Parts that are ordered with a "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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